

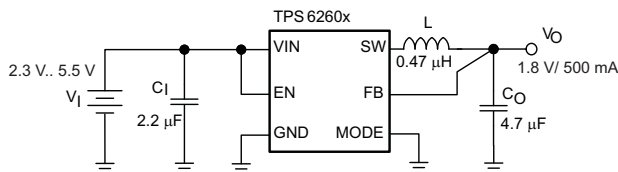
## 500-mA, 6-MHz SYNCHRONOUS STEP-DOWN CONVERTER IN CHIP SCALE PACKAGING

### FEATURES

- 89% Efficiency at 6MHz Operation
- Output Current Up to 500mA
- Wide  $V_{IN}$  Range From 2.3V to 5.5V
- 6MHz Regulated Frequency Operation
- *Best in Class* Load and Line Transient
- $\pm 1.5\%$  Total DC Voltage Accuracy
- Automatic PFM/PWM Mode Switching
- 30 $\mu$ A Quiescent Current
- 35ns Minimum On-Time
- Internal Soft Start, <200- $\mu$ s Start-Up Time
- Current Overload and Thermal Shutdown Protection
- Three Surface-Mount External Components Required (One MLCC Inductor, Two Ceramic Capacitors)
- Complete Sub 1-mm Component Profile Solution
- Total Solution Size <13 mm<sup>2</sup>
- Available in a 6-Pin NanoFree™ (CSP) Packaging

### APPLICATIONS

- Cell Phones, Smart-Phones
- PDAs, Pocket PCs
- WLAN and Bluetooth™ Applications
- DVB-H Tuner Applications
- Portable Hard Disk Drives
- DC/DC Micro Modules



**Figure 1. Smallest Solution Size Application  
(Fixed Output Voltage)**

### DESCRIPTION

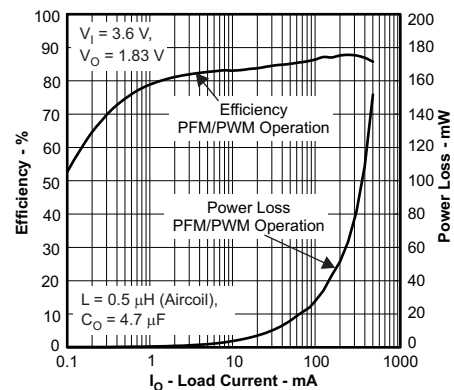
The TPS6260x device is a high-frequency synchronous step-down dc-dc converter optimized for battery-powered portable applications. Intended for low-power applications, the TPS6260x supports up to 500mA load current, and allows the use of low cost chip inductor and capacitors.

With a wide input voltage range of 2.3V to 5.5V, the device supports applications powered by Li-Ion batteries with extended voltage range. Different fixed voltage output versions are available from 1V to 2.5V.

The TPS6260x operates at a regulated 6-MHz switching frequency and enters the power-save mode operation at light load currents to maintain high efficiency over the entire load current range.

The PFM mode extends the battery life by reducing the quiescent current to 30 $\mu$ A (typ) during light load and standby operation. For noise-sensitive applications, the device can be forced into fixed frequency PWM mode by pulling the MODE pin high. In the shutdown mode, the current consumption is reduced to less than 1 $\mu$ A.

The TPS6260x is available in an 6-pin chip-scale package (CSP).



**Figure 2. Efficiency vs Load Current**



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoFree is a trademark of Texas Instruments.  
Bluetooth is a trademark of Bluetooth SIG, Inc.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2008, Texas Instruments Incorporated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## ORDERING INFORMATION<sup>(1)</sup>

| T <sub>A</sub> | PART NUMBER | OUTPUT VOLTAGE | PACKAGE | ORDERING <sup>(2)(3)</sup> | PACKAGE MARKING CHIP CODE |
|----------------|-------------|----------------|---------|----------------------------|---------------------------|
| -40°C to 85°C  | TPS62600    | 1.83V          | YFF-6   | TPS62600YFF                | G9                        |
|                | TPS62601    | 1.8V           |         | TPS62601YFF                | GA                        |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).

(2) The YFF package is available in tape and reel. Add a R suffix (TPS62600YFFR) to order quantities of 3000 parts. Add a T suffix (TPS62600YFFT) to order quantities of 250 parts.

(3) Internal tap points are available to facilitate output voltages in 25mV increments.

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                           |                                            | UNIT                             |
|---------------------------|--------------------------------------------|----------------------------------|
| V <sub>I</sub>            | Voltage at VIN, SW <sup>(2)</sup>          | -0.3 V to 7 V                    |
|                           | Voltage at FB <sup>(2)</sup>               | -0.3 V to 3.6 V                  |
|                           | Voltage at EN, MODE <sup>(2)</sup>         | -0.3 V to V <sub>I</sub> + 0.3 V |
|                           | Power dissipation                          | Internally limited               |
| T <sub>A</sub>            | Operating temperature range <sup>(3)</sup> | -40°C to 85°C                    |
| T <sub>J</sub> (max)      | Maximum operating junction temperature     | 150°C                            |
| T <sub>stg</sub>          | Storage temperature range                  | -65°C to 150°C                   |
| ESD rating <sup>(4)</sup> | Human body model                           | 2 kV                             |
|                           | Charge device model                        | 1 kV                             |
|                           | Machine model                              | 200 V                            |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T<sub>A(max)</sub>) is dependent on the maximum operating junction temperature (T<sub>J(max)</sub>), the maximum power dissipation of the device in the application (P<sub>D(max)</sub>), and the junction-to-ambient thermal resistance of the part/package in the application (θ<sub>JA</sub>), as given by the following equation: T<sub>A(max)</sub> = T<sub>J(max)</sub> - (θ<sub>JA</sub> × P<sub>D(max)</sub>).

(4) The human body model is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each pin. The machine model is a 200-pF capacitor discharged directly into each pin.

## DISSIPATION RATINGS<sup>(1)</sup>

| PACKAGE | R <sub>θJA</sub> <sup>(2)</sup> | R <sub>θJB</sub> <sup>(2)</sup> | POWER RATING<br>T <sub>A</sub> ≤ 25°C | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C |
|---------|---------------------------------|---------------------------------|---------------------------------------|------------------------------------------------|
| YFF-6   | 125°C/W                         | 53°C/W                          | 800mW                                 | 8mW/°C                                         |

(1) Maximum power dissipation is a function of T<sub>J(max)</sub>, θ<sub>JA</sub> and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = [T<sub>J(max)</sub> - T<sub>A</sub>] / θ<sub>JA</sub>.

(2) This thermal data is measured with high-K board (4 layers board according to JESD51-7 JEDEC standard).

## ELECTRICAL CHARACTERISTICS

 $V_I = 3.6V$ ,  $V_O = 1.83V$ ,  $EN = 1.8V$ ,  $T_A = -40^{\circ}C$  to  $85^{\circ}C$ , typical values are at  $T_A = 25^{\circ}C$  (unless otherwise noted)

| PARAMETER                 |                                                    |                      | TEST CONDITIONS                                                                   | MIN                    | TYP              | MAX                    | UNIT            |
|---------------------------|----------------------------------------------------|----------------------|-----------------------------------------------------------------------------------|------------------------|------------------|------------------------|-----------------|
| SUPPLY CURRENT            |                                                    |                      |                                                                                   |                        |                  |                        |                 |
| V <sub>I</sub>            | Input voltage range                                |                      |                                                                                   | 2.3                    |                  | 5.5                    | V               |
| I <sub>Q</sub>            | Operating quiescent current                        |                      | I <sub>O</sub> = 0mA. PFM mode enabled, device not switching                      | 30                     |                  | 45                     | μA              |
|                           |                                                    |                      | I <sub>O</sub> = 0mA, L = 0.47μH (Aircoil)<br>Forced PWM operation                | 6.5                    |                  |                        | mA              |
| I <sub>(SD)</sub>         | Shutdown current                                   |                      | EN = GND                                                                          | 0.2                    |                  | 1                      | μA              |
| UVLO                      | Undervoltage lockout threshold                     |                      |                                                                                   | 2.05                   |                  | 2.1                    | V               |
| ENABLE, MODE              |                                                    |                      |                                                                                   |                        |                  |                        |                 |
| V <sub>IH</sub>           | High-level input voltage                           |                      |                                                                                   | 1                      |                  |                        | V               |
| V <sub>IL</sub>           | Low-level input voltage                            |                      |                                                                                   |                        |                  | 0.4                    | V               |
| I <sub>lk</sub>           | Input leakage current                              |                      | Input connected to GND or VIN                                                     | 0.01                   |                  | 1                      | μA              |
| POWER SWITCH              |                                                    |                      |                                                                                   |                        |                  |                        |                 |
| r <sub>DS(on)</sub>       | P-channel MOSFET on resistance                     |                      | V <sub>I</sub> = V <sub>(GS)</sub> = 3.6V                                         | 310                    |                  |                        | mΩ              |
|                           |                                                    |                      | V <sub>I</sub> = V <sub>(GS)</sub> = 2.5V                                         | 380                    |                  |                        | mΩ              |
| I <sub>lk</sub>           | P-channel leakage current, PMOS                    |                      | V <sub>(DS)</sub> = 5.5V, -40°C ≤ T <sub>J</sub> ≤ 85°C                           |                        |                  | 1                      | μA              |
| r <sub>DS(on)</sub>       | N-channel MOSFET on resistance                     |                      | V <sub>I</sub> = V <sub>(GS)</sub> = 3.6V                                         | 250                    |                  |                        | mΩ              |
|                           |                                                    |                      | V <sub>I</sub> = V <sub>(GS)</sub> = 2.5V                                         | 320                    |                  |                        | mΩ              |
| I <sub>lk</sub>           | N-channel leakage current, NMOS                    |                      | V <sub>(DS)</sub> = 5.5V, -40°C ≤ T <sub>J</sub> ≤ 85°C                           |                        |                  | 2                      | μA              |
|                           | P-MOS current limit                                |                      | 2.3V ≤ V <sub>I</sub> ≤ 5.5V. Open loop                                           | 900                    | 1000             | 1100                   | mA              |
|                           | Input current limit under short-circuit conditions |                      | V <sub>O</sub> = 0 , L = 0.47μH                                                   |                        | 30               |                        | mA              |
|                           | Thermal shutdown                                   |                      |                                                                                   |                        | 140              |                        | °C              |
|                           | Thermal shutdown hysteresis                        |                      |                                                                                   |                        | 10               |                        | °C              |
| OSCILLATOR                |                                                    |                      |                                                                                   |                        |                  |                        |                 |
| f <sub>SW</sub>           | Oscillator frequency                               | TPS62600<br>TPS62601 | I <sub>O</sub> = 0mA, L = 0.47μH. Forced PWM operation                            | 5.4                    | 6                | 6.6                    | MHz             |
| OUTPUT                    |                                                    |                      |                                                                                   |                        |                  |                        |                 |
| V <sub>(OUT)</sub>        | Regulated DC output voltage                        | TPS62600<br>TPS62601 | 2.5V ≤ V <sub>I</sub> ≤ 5.5V, 0mA ≤ I <sub>O</sub> ≤ 500mA<br>PFM/PWM operation   | 0.985×V <sub>NOM</sub> | V <sub>NOM</sub> | 1.025×V <sub>NOM</sub> | V               |
|                           |                                                    |                      | 2.5V ≤ V <sub>I</sub> ≤ 5.5V, 0 mA ≤ I <sub>O</sub> ≤ 500mA<br>PWM operation      | 0.985×V <sub>NOM</sub> | V <sub>NOM</sub> | 1.015×V <sub>NOM</sub> | V               |
|                           | Line regulation                                    |                      | V <sub>I</sub> = V <sub>O</sub> + 0.5V (min 2.3V) to 5.5V, I <sub>O</sub> = 200mA |                        | 0.25             |                        | %/V             |
|                           | Load regulation                                    |                      | I <sub>O</sub> = 0mA to 500mA                                                     |                        | -0.0003          |                        | %/mA            |
| Feedback input resistance |                                                    |                      |                                                                                   | 460                    |                  |                        | kΩ              |
| t <sub>on(MIN)</sub>      | Minimum on-time (P-channel MOSFET)                 |                      |                                                                                   | 35                     |                  |                        | ns              |
| ΔV <sub>O</sub>           | Power-save mode ripple voltage                     | TPS62600<br>TPS62601 | I <sub>O</sub> = 1mA                                                              | 0.015×V <sub>NOM</sub> |                  |                        | V <sub>PP</sub> |
|                           | Start-up time                                      |                      | I <sub>O</sub> = 0mA, Time from active EN to V <sub>O</sub>                       | 180                    |                  |                        | μs              |

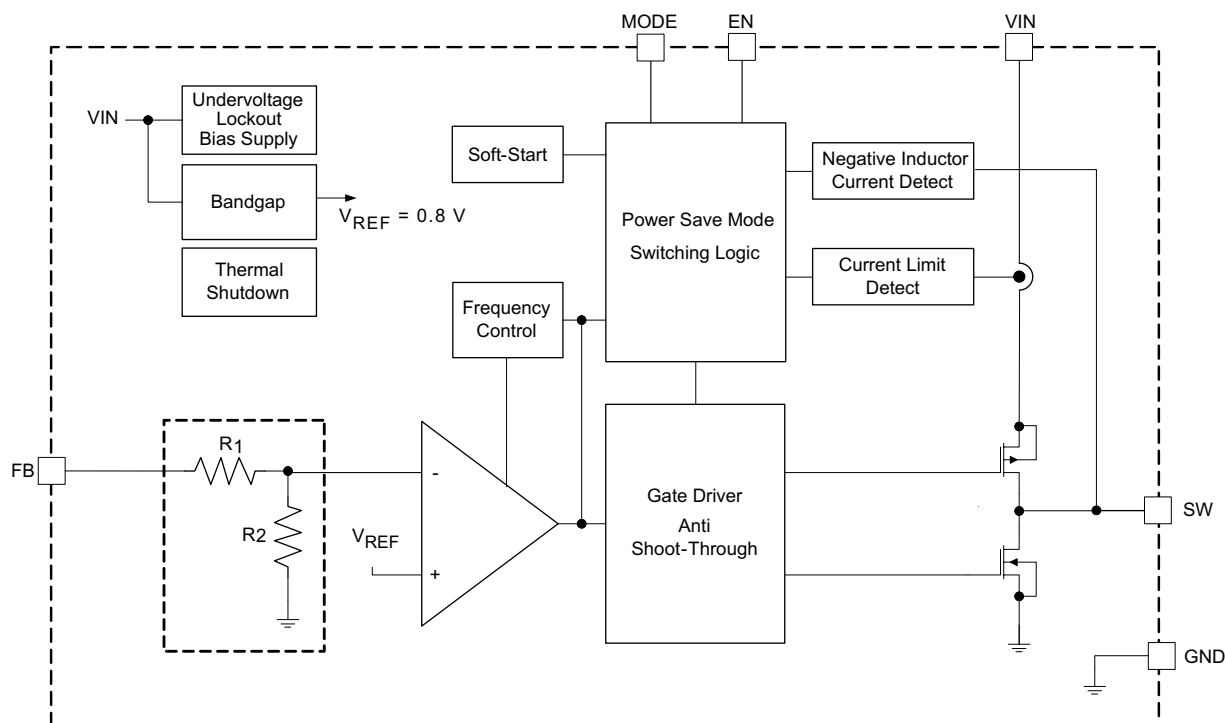
## PIN ASSIGNMENTS



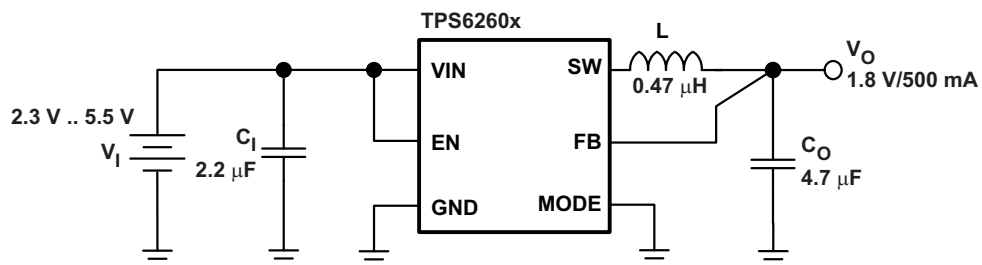
## TERMINAL FUNCTIONS

| TERMINAL |     | I/O | DESCRIPTION                                                                                                                                                                                                                                                       |
|----------|-----|-----|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME     | NO. |     |                                                                                                                                                                                                                                                                   |
| FB       | C1  | I   | Output feedback sense input. Connect FB to the converter's output.                                                                                                                                                                                                |
| VIN      | A2  | I   | Power supply input.                                                                                                                                                                                                                                               |
| SW       | B1  | I/O | This is the switch pin of the converter and is connected to the drain of the internal Power MOSFETs.                                                                                                                                                              |
| EN       | B2  | I   | This is the enable pin of the device. Connecting this pin to ground forces the device into shutdown mode. Pulling this pin to $V_I$ enables the device. This pin must not be left floating and must be terminated.                                                |
| MODE     | A1  | I   | This is the mode selection pin of the device. This pin must not be left floating and must be terminated.                                                                                                                                                          |
|          |     |     | MODE = LOW: The device is operating in fixed frequency pulse width modulation mode (PWM) at high-load currents and in pulse frequency modulation mode (PFM) at light load currents.<br>MODE = HIGH: Low-noise mode enabled, fixed frequency PWM operation forced. |
| GND      | C2  | –   | Ground pin.                                                                                                                                                                                                                                                       |

## FUNCTIONAL BLOCK DIAGRAM



## PARAMETER MEASUREMENT INFORMATION



List of components:

- $L$  = MURATA LQM21PN1R0NGR
- $C_I$  = MURATA GRM155R60J225ME15 (2.2 $\mu\text{F}$ , 6.3V, 0402, X5R)
- $C_O$  = MURATA GRM155R60G475ME47 (4.7 $\mu\text{F}$ , 4V, 0402, X5R)

## TYPICAL CHARACTERISTICS

Table of Graphs

|              |                                       |                  | FIGURE                          |
|--------------|---------------------------------------|------------------|---------------------------------|
| $\eta$       | Efficiency                            | vs Load current  | 3, 4, 5                         |
|              |                                       | vs Input voltage | 6                               |
|              | Combined line/load transient response |                  | 7, 8                            |
|              | Load transient response               |                  | 9, 10, 11, 12<br>13, 14, 15, 16 |
| $V_O$        | DC output voltage                     | vs Load current  | 17                              |
| $I_Q$        | No load quiescent current             | vs Input voltage | 18                              |
| $f_s$        | Switching frequency                   | vs Temperature   | 19                              |
| $r_{DS(on)}$ | P-channel MOSFET $r_{DS(on)}$         | vs Input voltage | 20                              |
|              | N-channel MOSFET $r_{DS(on)}$         | vs Input voltage | 21                              |
|              | PWM operation                         |                  | 22                              |
|              | Power-save mode operation             |                  | 23                              |
|              | Start-up                              |                  | 24                              |

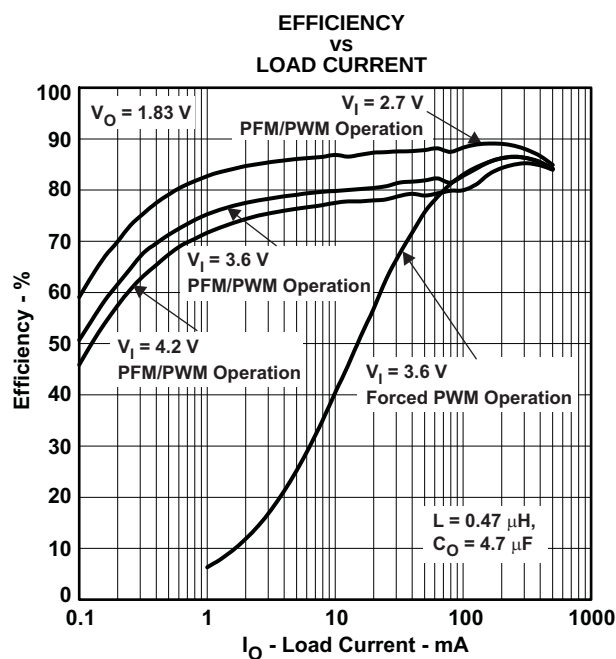


Figure 3.

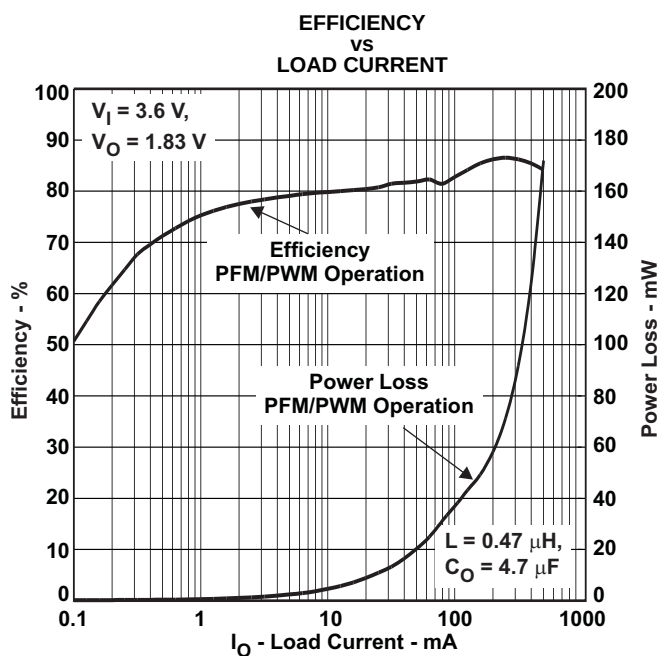


Figure 4.

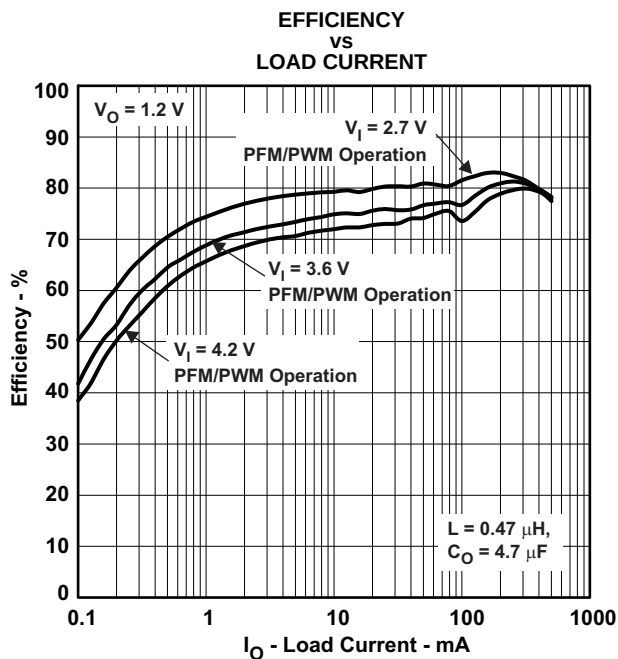


Figure 5.

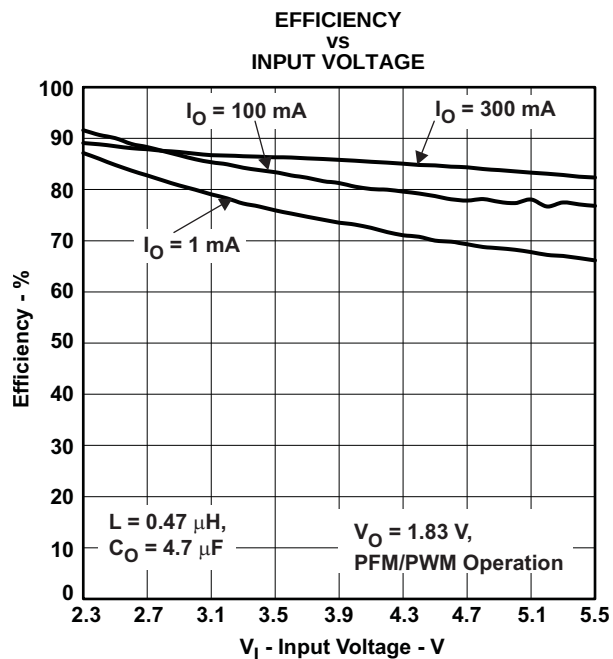


Figure 6.

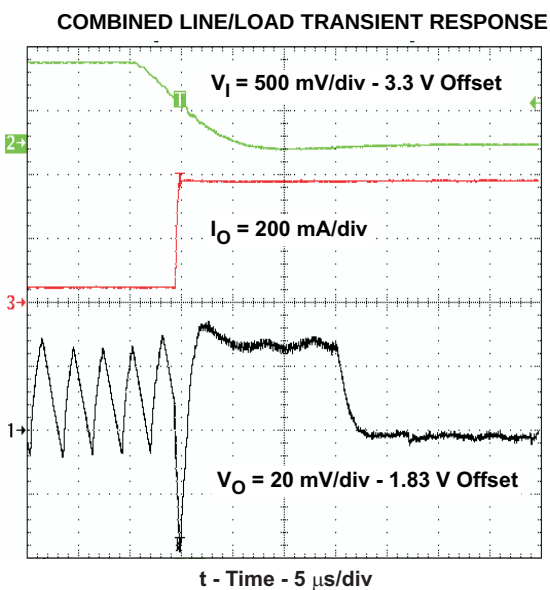


Figure 7.

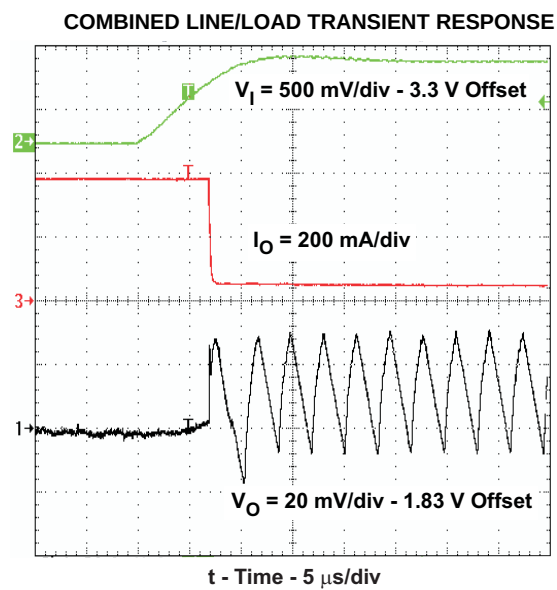


Figure 8.

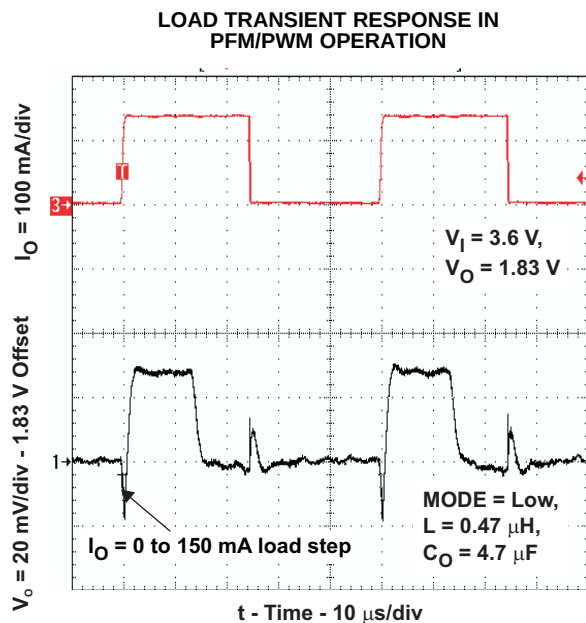


Figure 9.

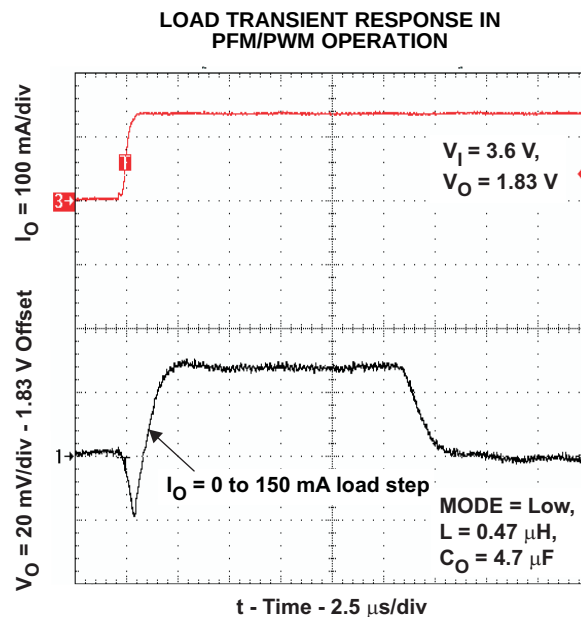


Figure 10.

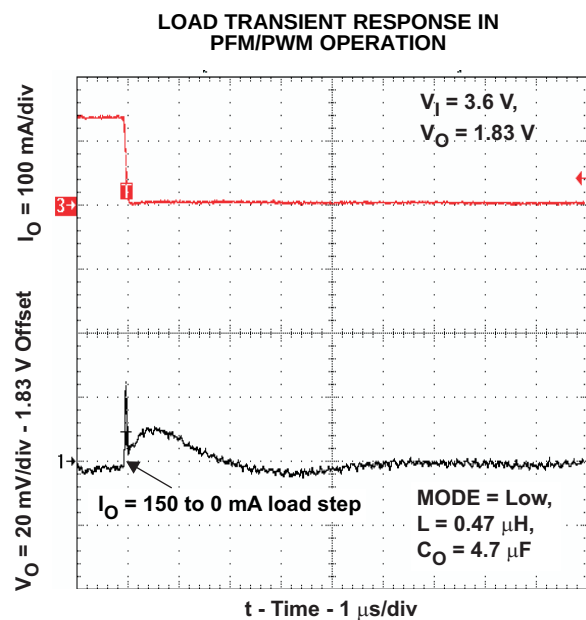


Figure 11.

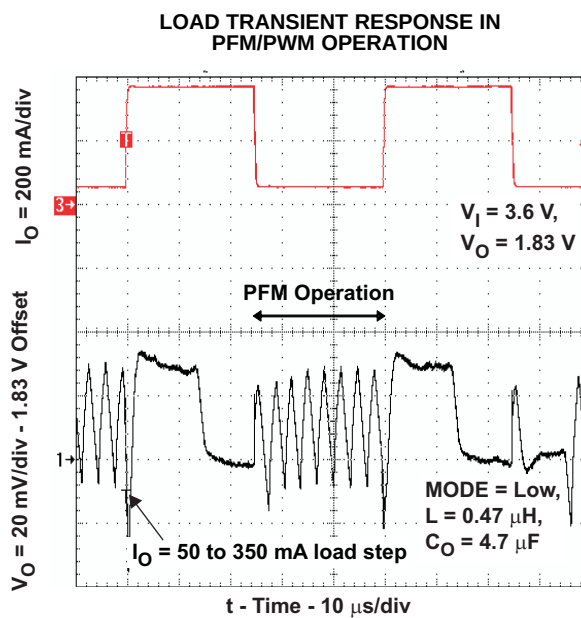


Figure 12.

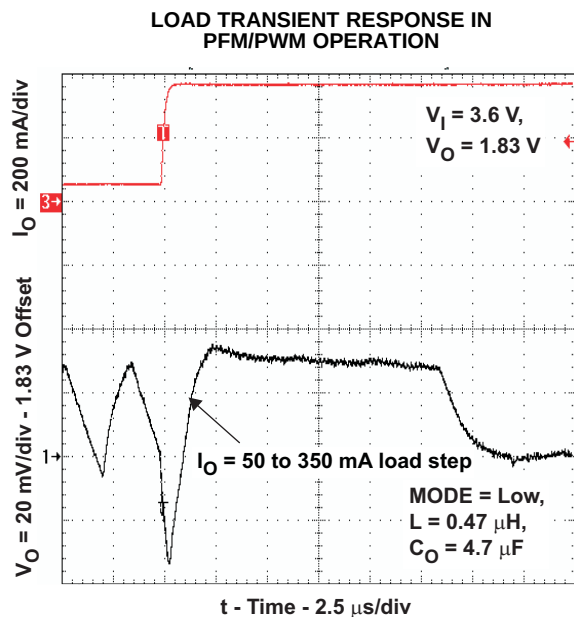


Figure 13.

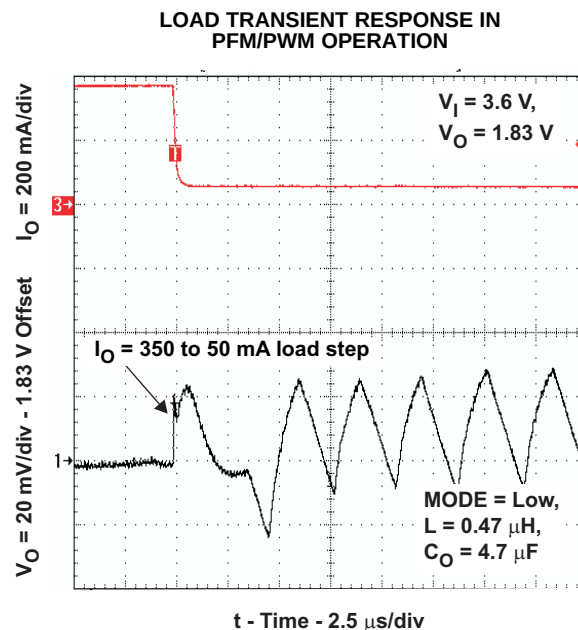


Figure 14.

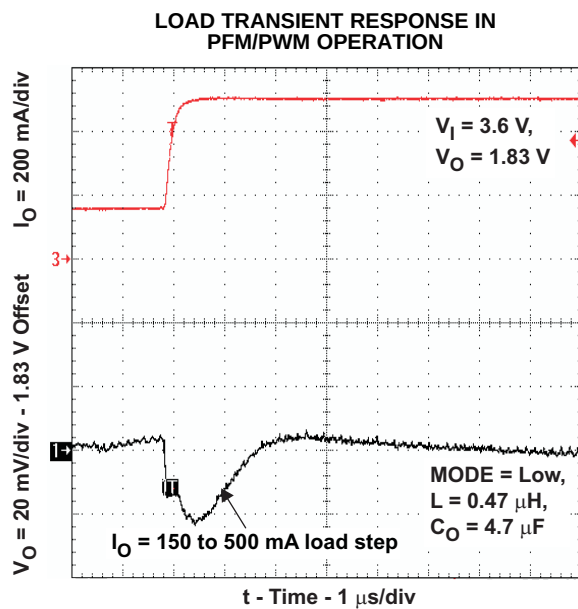


Figure 15.

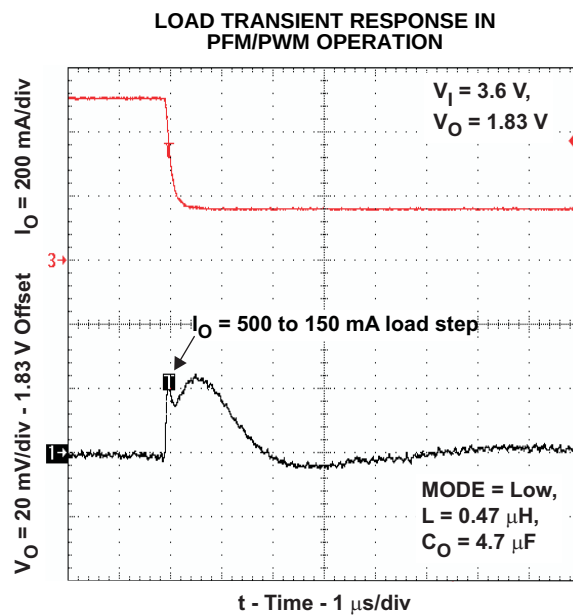


Figure 16.

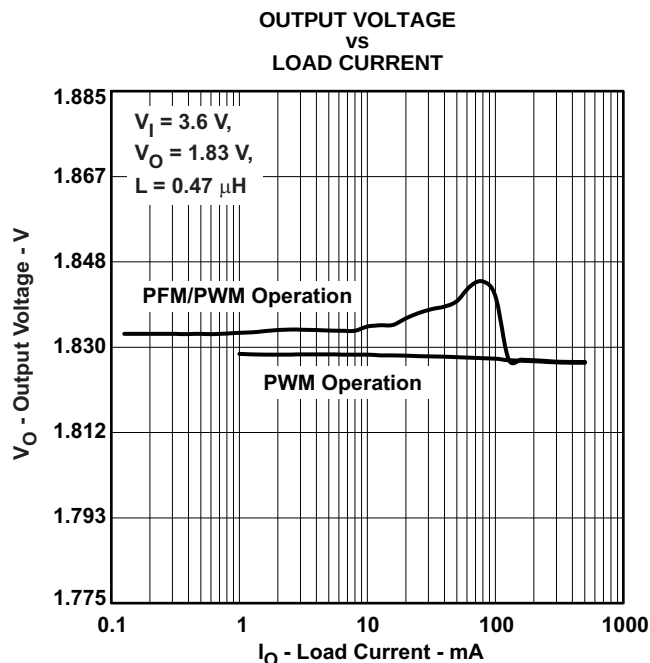


Figure 17.

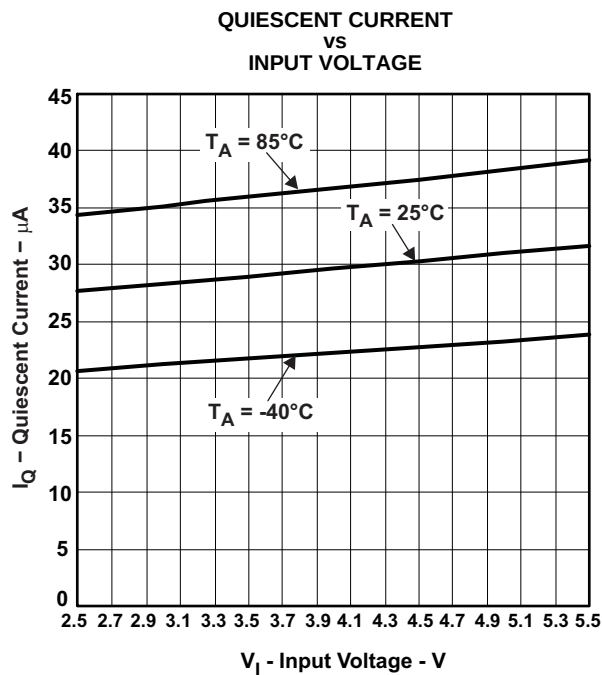


Figure 18.

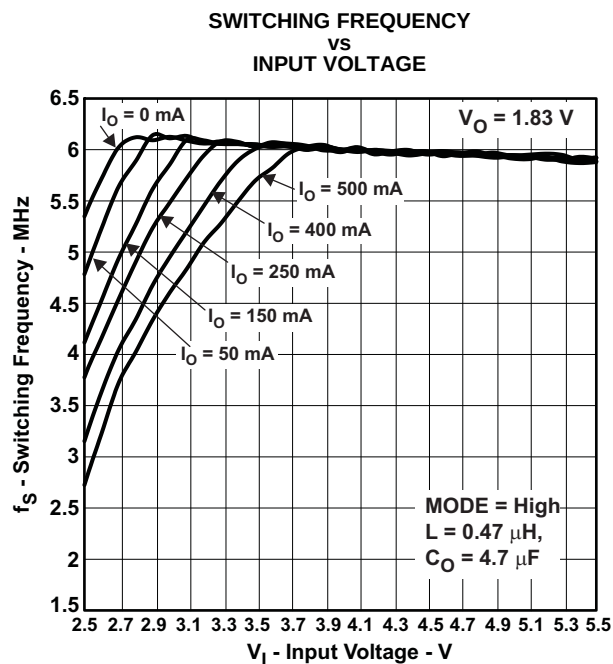


Figure 19.

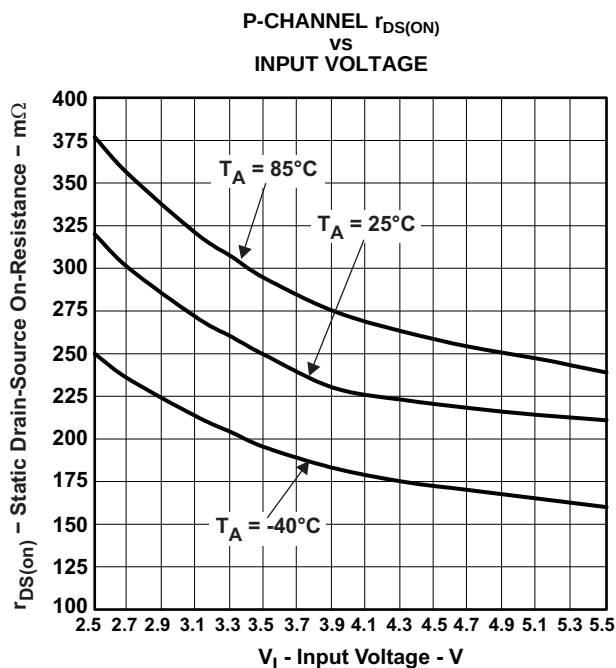


Figure 20.

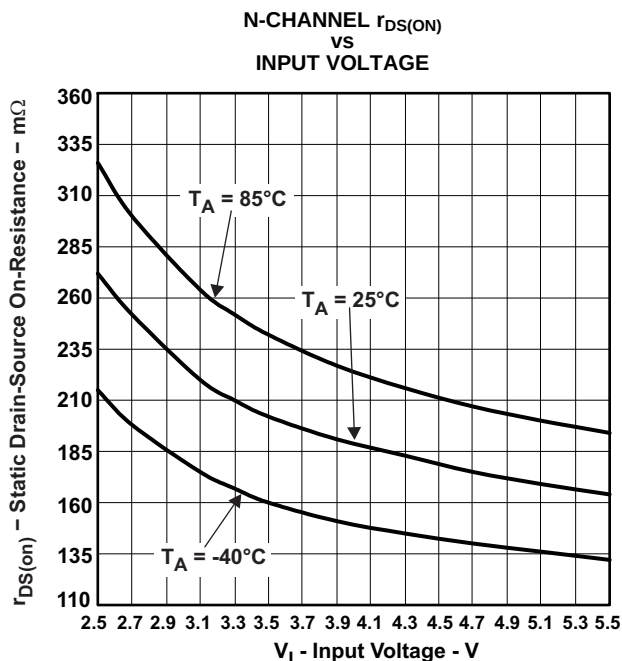


Figure 21.

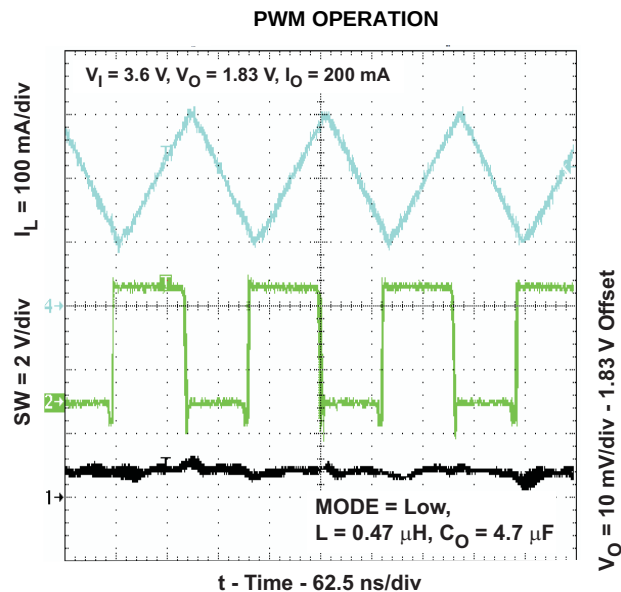


Figure 22.

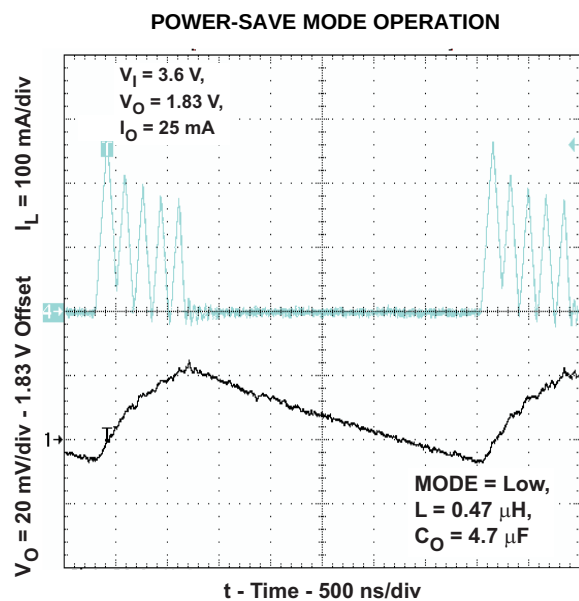


Figure 23.

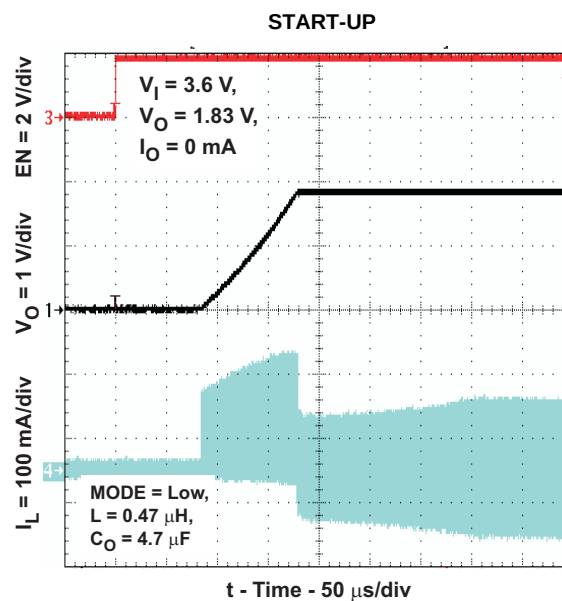


Figure 24.

## DETAILED DESCRIPTION

### OPERATION

The TPS6260x is a synchronous step-down converter typically operates at a regulated 6-MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. At light load currents, the TPS6260x converter operates in power-save mode with pulse frequency modulation (PFM).

The converter uses a unique frequency locked ring oscillating modulator to achieve *best-in-class* load and line response and allows the use of tiny inductors and small ceramic input and output capacitors. At the beginning of each switching cycle, the P-channel MOSFET switch is turned on and the inductor current ramps up rising the output voltage until the main comparator trips, then the control logic turns off the switch.

One key advantage of the non-linear architecture is that there is no traditional feed-back loop. The loop response to change in  $V_O$  is essentially instantaneous, which explains the transient response. The absence of a traditional, high-gain compensated linear loop means that the TPS6260x is inherently stable over a range of L and  $C_O$ .

The device integrates two current limits, one in the P-channel MOSFET and another one in the N-channel MOSFET. When the current in the P-channel MOSFET reaches its current limit, the P-channel MOSFET is turned off and the N-channel MOSFET is turned on. When the current in the N-channel MOSFET is above the N-MOS current limit threshold, the N-channel MOSFET remains on until the current drops below its current limit.

The current limit in the N-channel MOSFET is important for small duty-cycle operation when the current in the inductor does not decrease because of the P-channel MOSFET current limit delay, or because of start-up conditions where the output voltage is low.

### SWITCHING FREQUENCY

The magnitude of the internal ramp, which is generated from the duty cycle, reduces for duty cycles either set of 50%. Thus, there is less overdrive on the main comparator inputs which tends to slow the conversion down. The intrinsic maximum operating frequency of the converter is about 10MHz to 12MHz, which is controlled to circa. 6MHz by a frequency locked loop.

When high or low duty cycles are encountered, the loop runs out of range and the conversion frequency falls below 6MHz. The tendency is for the converter to operate more towards a "constant inductor peak current" rather than a "constant frequency". In addition to this behavior which is observed at high duty cycles, it is also noted at low duty cycles.

When the converter is required to operate towards the 6MHz nominal at extreme duty cycles, the application can be assisted by decreasing the ratio of inductance (L) to the output capacitor's equivalent serial inductance (ESL). This increases the *ESL step* seen at the main comparator's feed-back input thus decreasing its propagation delay, hence increasing the switching frequency.

### POWER-SAVE MODE

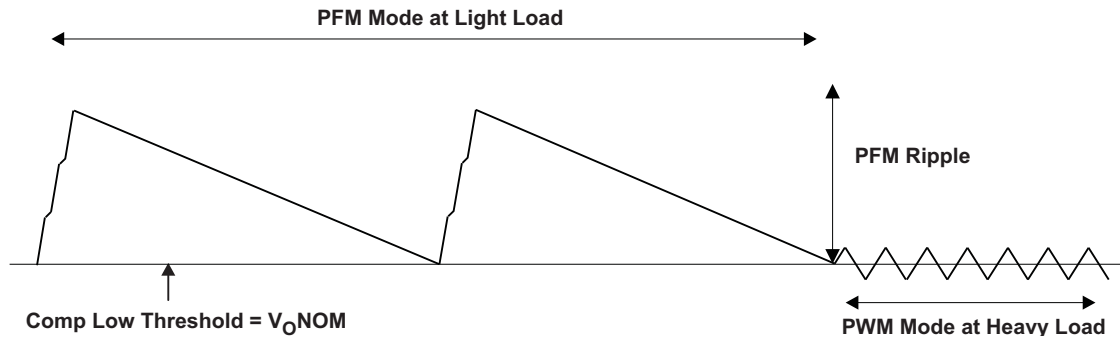
With decreasing load current, the device automatically switches into pulse skipping operation in which the power stage operates intermittently based on load demand. By running cycles periodically, the switching losses are minimized, and the device runs with a minimum quiescent current and maintaining high efficiency. The converter positions the dc output voltage approximately 0.5% above the nominal output voltage under light load conditions. This voltage positioning feature minimizes voltage drops caused by a sudden load step.

When in power-save mode, the converter resumes its operation when the output voltage trips below the nominal voltage. It ramps up the output voltage with a minimum of three pulses and goes into power-save mode when the inductor current has returned to a zero steady state. As a consequence of the dynamic voltage positioning in the power-save mode, the average output voltage is slightly higher than its nominal value in PWM mode. For a load transient from light load to heavy load, the logic returns the regulated output voltage to nominal after 64 continuous cycles.

The output current at which the PFM/PWM transition occurs is approximated by [Equation 1](#):

$$I_{\text{PFM/PWM}} = \frac{V_O}{V_I} \times \frac{V_I - V_O}{2 \times L \times f_{\text{SW}}} \quad (1)$$

- $I_{\text{PFM/PWM}}$  : output current at which PFM/PWM transition occurs
- $f_{\text{SW}}$  : switching frequency (6-MHz typical)
- $L$  : inductor value



**Figure 25. Operation in PFM Mode and Transfer to PWM Mode**

## MODE SELECTION

The MODE pin allows to select the operating mode of the device. Connecting this pin to GND enables the automatic PWM and power-save mode operation. The converter operates in fixed frequency PWM mode at moderate to heavy loads and in the PFM mode during light loads, which maintains high efficiency over a wide load current range.

Pulling the MODE pin high forces the converter to operate in the PWM mode even at light load currents. The advantage is that the converter operates with a fixed frequency that allows simple filtering of the switching frequency for noise-sensitive applications. In this mode, the efficiency is lower compared to the power-save mode during light loads.

For additional flexibility, it is possible to switch from power-save mode to forced PWM mode during operation. This allows efficient power management by adjusting the operation of the converter to the specific system requirements.

## ENABLE

The device starts operation when EN is set high and starts up with the soft start as previously described.

Pulling the EN pin low forces the device into shutdown, with a shutdown quiescent current of typically 0.1μA. In this mode, the P and N-channel MOSFETs are turned off, the internal resistor feedback divider is disconnected, and the entire internal-control circuitry is switched off. For proper operation, the EN pin must be terminated and must not be left floating.

## SOFT START

The TPS6260x has an internal soft-start circuit that limits the inrush current during start-up. This limits input voltage drops when a battery or a high-impedance power source is connected to the input of the converter. The soft-start system progressively increases the on-time from a minimum pulse-width of 30ns as a function of the output voltage. This mode of operation continues for c.a. 180 $\mu$ s after enable. Should the output voltage not have reached its target value by this time, such as in the case of heavy load, the soft-start transitions to a second mode of operation.

The converter then operates in a current limit mode, specifically the P-MOS current limit is set to half the nominal limit, and the N-channel MOSFET remains on until the inductor current has reset. After a further 100  $\mu$ s, the device ramps up to the full current limit operation if the output voltage has risen above 0.7V (approximately). Therefore, the start-up time mainly depends on the output capacitor and load current.

## UNDERVOLTAGE LOCKOUT

The undervoltage lockout circuit prevents the device from misoperation at low input voltages. It prevents the converter from turning on the switch or rectifier MOSFET under undefined conditions. The TPS6260x device have a UVLO threshold set to 2.05V (typical). Fully functional operation is permitted down to 2.1V input voltage.

## SHORT-CIRCUIT PROTECTION

As soon as the output voltage falls below 0.7V (approximately), the converter current limit is reduced to half of the nominal value. Because the short-circuit protection is enabled during start-up, the device does not deliver more than half of its nominal current limit until the output voltage exceeds 0.7V (approximately). This needs to be considered when a load acting as a current sink is connected to the output of the converter.

## THERMAL SHUTDOWN

As soon as the junction temperature,  $T_J$ , exceeds typically 140°C, the device goes into thermal shutdown. In this mode, the P- and N-channel MOSFETs are turned off. The device continues its operation when the junction temperature again falls below typically 130°C.

## APPLICATION INFORMATION

### INDUCTOR SELECTION

The TPS6260x series of step-down converters have been designed to operate with an effective inductance value in the range of 0.3μH to 1.3μH and with output capacitors in the range of 4.7μF to 10μF. The internal compensation is optimized to operate with an output filter of  $L = 0.47\mu\text{H}$  and  $C_O = 4.7\mu\text{F}$ . Larger or smaller inductor values can be used to optimize the performance of the device for specific operation conditions. For more details, see the *CHECKING LOOP STABILITY* section.

The inductor value affects its peak-to-peak ripple current, the PWM-to-PFM transition point, the output voltage ripple and the efficiency. The selected inductor has to be rated for its dc resistance and saturation current. The inductor ripple current ( $\Delta I_L$ ) decreases with higher inductance and increases with higher  $V_I$  or  $V_O$ .

$$\Delta I_L = \frac{V_O}{V_I} \times \frac{V_I - V_O}{L \times f_{SW}} \quad \Delta I_{L(\text{MAX})} = I_{O(\text{MAX})} + \frac{\Delta I_L}{2} \quad (2)$$

with:  $f_{SW}$  = switching frequency (6 MHz typical)

$L$  = inductor value

$\Delta I_L$  = peak-to-peak inductor ripple current

$I_{L(\text{MAX})}$  = maximum inductor current

In high-frequency converter applications, the efficiency is essentially affected by the inductor AC resistance (i.e. quality factor) and to a smaller extent by the inductor DCR value. To achieve high efficiency operation, care should be taken in selecting inductors featuring a quality factor above 25 at the switching frequency. Increasing the inductor value produces lower RMS currents, but degrades transient response. For a given physical inductor size, increased inductance usually results in an inductor with lower saturation current.

The total losses of the coil consist of both the losses in the DC resistance ( $R_{DC}$ ) and the following frequency-dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

The following inductor series from different suppliers have been used with the TPS6260x converters.

**Table 1. List of Inductors**

| MANUFACTURER   | SERIES            | DIMENSIONS                   |
|----------------|-------------------|------------------------------|
| MURATA         | LQM21P_J0         | 2.0 x 1.2 x 1.0 max. height  |
|                | LQM21P_C0         | 2.0 x 1.2 x 0.55 max. height |
| HITACHI METALS | HSLI-201210AG-R47 | 2.0 x 1.2 x 1.0 max. height  |
|                | HSLI-201210SW-R85 | 2.0 x 1.2 x 1.0 max. height  |
|                | JSLI-201610AG-R70 | 2.0 x 1.6 x 1.0 max. height  |
| TOKO           | MDT2012-CX1R0-R   | 2.0 x 1.2 x 1.0 max. height  |

## OUTPUT CAPACITOR SELECTION

The advanced fast-response voltage mode control scheme of the TPS6260x allows the use of tiny ceramic capacitors. Ceramic capacitors with low ESR values have the lowest output voltage ripple and are recommended. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance over temperature, become resistive at high frequencies.

At nominal load current, the device operates in PWM mode and the overall output voltage ripple is the sum of the voltage step caused by the output capacitor ESL and the ripple current flowing through the output capacitor impedance.

At light loads, the device operates in power-save mode and the output voltage ripple is independent of the output capacitor value. The output voltage ripple is set by the internal comparator thresholds and propagation delays. The typical output voltage ripple is 1.5% of the nominal output voltage  $V_O$ .

## INPUT CAPACITOR SELECTION

Because of the nature of the buck converter having a pulsating input current, a low ESR input capacitor is required to prevent large voltage transients that can cause misbehavior of the device or interferences with other circuits in the system. For most applications, a 2.2- $\mu$ F capacitor is sufficient.

Take care when using only ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, such as from a wall adapter, a load step at the output can induce ringing at the VIN pin. This ringing can couple to the output and be mistaken as loop instability or could even damage the part. Additional "bulk" capacitance (electrolytic or tantalum) should in this circumstance be placed between  $C_I$  and the power source lead to reduce ringing than can occur between the inductance of the power source leads and  $C_I$ .

## CHECKING LOOP STABILITY

The first step of circuit and stability evaluation is to look from a steady-state perspective at the following signals:

- Switching node, SW
- Inductor current,  $I_L$
- Output ripple voltage,  $V_{O(AC)}$

These are the basic signals that need to be measured when evaluating a switching converter. When the switching waveform shows large duty cycle jitter or the output voltage or inductor current shows oscillations, the regulation loop may be unstable. This is often a result of board layout and/or L-C combination.

As a next step in the evaluation of the regulation loop, the load transient response is tested. The time between the application of the load transient and the turn on of the P-channel MOSFET, the output capacitor must supply all of the current required by the load.  $V_O$  immediately shifts by an amount equal to  $\Delta I_{(LOAD)} \times ESR$ , where ESR is the effective series resistance of  $C_O$ .  $\Delta I_{(LOAD)}$  begins to charge or discharge  $C_O$  generating a feedback error signal used by the regulator to return  $V_O$  to its steady-state value. The results are most easily interpreted when the device operates in PWM mode.

During this recovery time,  $V_O$  can be monitored for settling time, overshoot or ringing that helps judge the converter's stability. Without any ringing, the loop has usually more than 45° of phase margin.

Because the damping factor of the circuitry is directly related to several resistive parameters (e.g., MOSFET  $r_{DS(on)}$ ) that are temperature dependant, the loop stability analysis has to be done over the input voltage range, load current range, and temperature range.

## LAYOUT CONSIDERATIONS

As for all switching power supplies, the layout is an important step in the design. High-speed operation of the TPS6260x devices demand careful attention to PCB layout. Care must be taken in board layout to get the specified performance. If the layout is not carefully done, the regulator could show poor line and/or load regulation, stability and switching frequency issues as well as EMI problems. It is critical to provide a low inductance, impedance ground path. Therefore, use wide and short traces for the main current paths.

The input capacitor should be placed as close as possible to the IC pins as well as the inductor and output capacitor. In order to get an optimum *ESL step*, the output voltage feedback point (FB) should be taken in the output capacitor path, approximately 1mm away for it. The feed-back line should be routed away from noisy components and traces (e.g. SW line).

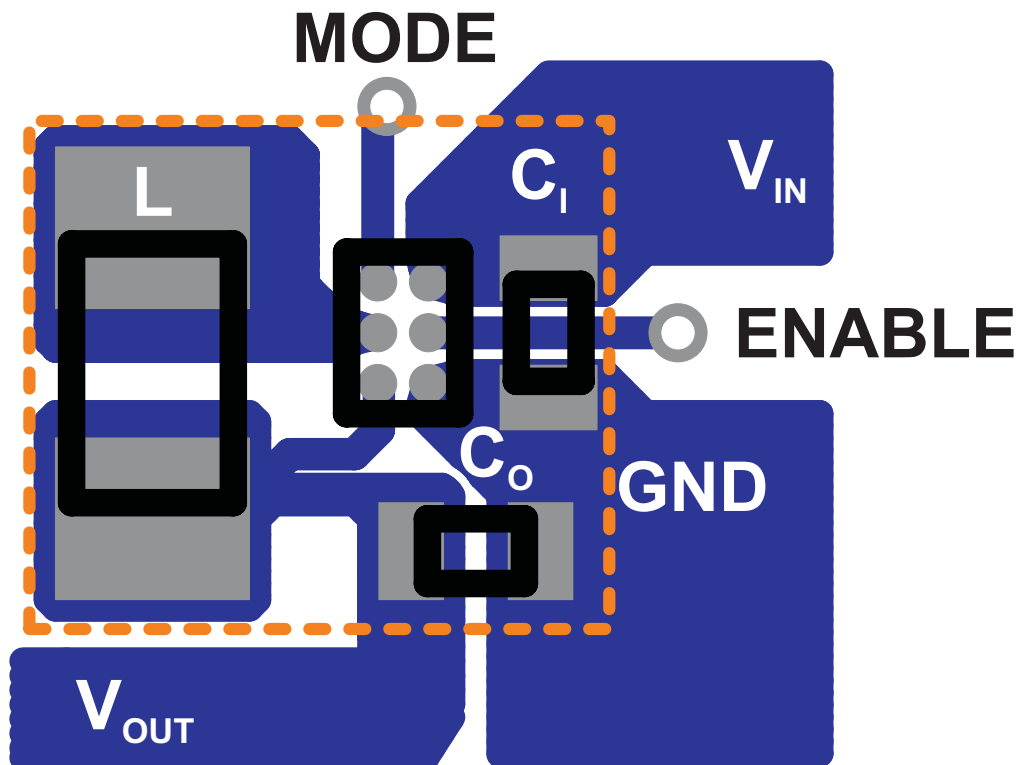


Figure 26. Suggested Layout (Top)

## THERMAL INFORMATION

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependant issues such as thermal coupling, airflow, added heat sinks, and convection surfaces, and the presence of other heat-generating components, affect the power-dissipation limits of a given component

Three basic approaches for enhancing thermal performance are listed below:

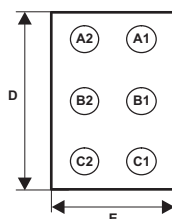
- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB
- Introducing airflow in the system

The maximum recommended junction temperature ( $T_J$ ) of the TPS6260x devices is 125°C. The thermal resistance of the 6-pin CSP package (YFF-6) is  $R_{\theta JA} = 125^\circ\text{C/W}$ . Regulator operation is specified to a maximum ambient temperature  $T_A$  of 85°C. Therefore, the maximum power dissipation is about 320 mW.

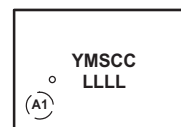
$$P_{D(\text{MAX})} = \frac{T_{J(\text{MAX})} - T_A}{R_{\theta JA}} = \frac{125^\circ\text{C} - 85^\circ\text{C}}{125^\circ\text{C/W}} = 320\text{mW} \quad (3)$$

## PACKAGE SUMMARY

**CHIP SCALE PACKAGE  
(BOTTOM VIEW)**



**CHIP SCALE PACKAGE  
(TOP VIEW)**



Code:

- YM — Year Month date Code
- S — Assembly site code
- CC — Chip code
- LLLL — Lot trace code

## CHIP SCALE PACKAGE DIMENSIONS

The TPS6260x device is available in an 6-bump chip scale package (YFF, NanoFree™). The package dimensions are given as:

- $D = 1.290 \pm 0.05 \text{ mm}$
- $E = 0.916 \pm 0.05 \text{ mm}$

PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS62601YFFT</a> | Active        | Production           | DSBGA (YFF)   6 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | GA                  |
| TPS62601YFFT.B               | Active        | Production           | DSBGA (YFF)   6 | 250   SMALL T&R       | Yes         | SNAGCU                               | Level-1-260C-UNLIM                | -40 to 85    | GA                  |

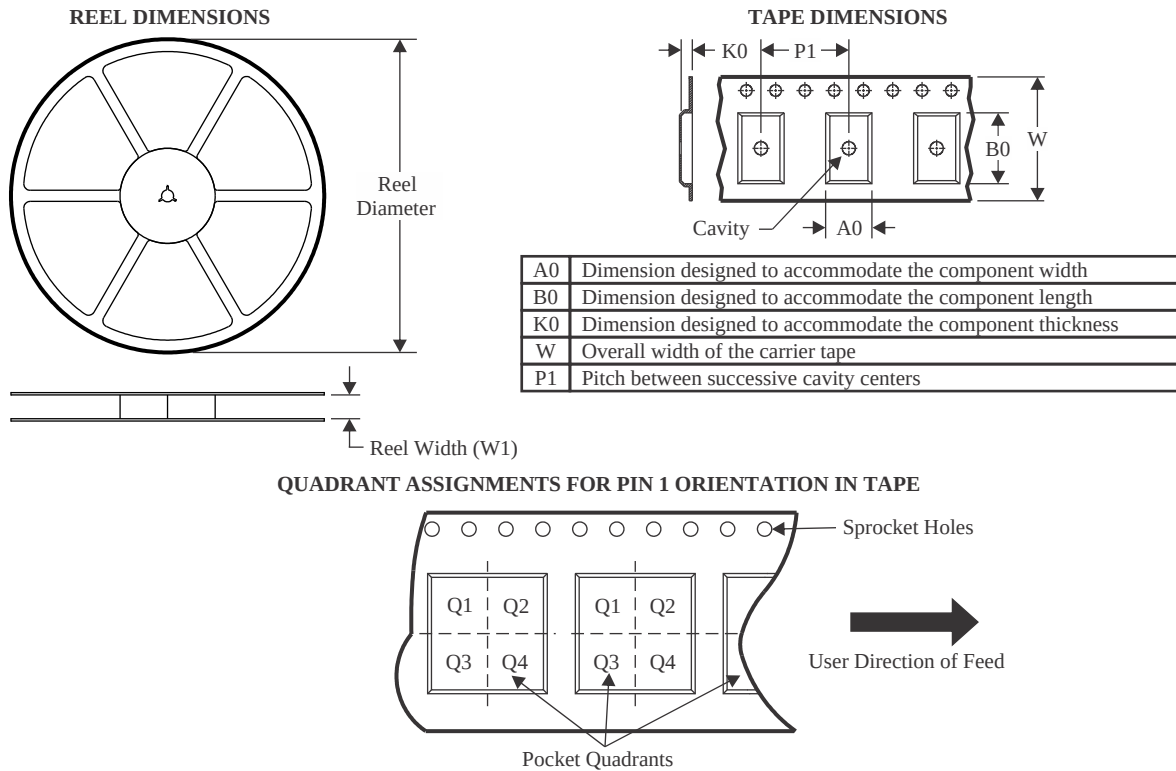
- <sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).
- <sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- <sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- <sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- <sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- <sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

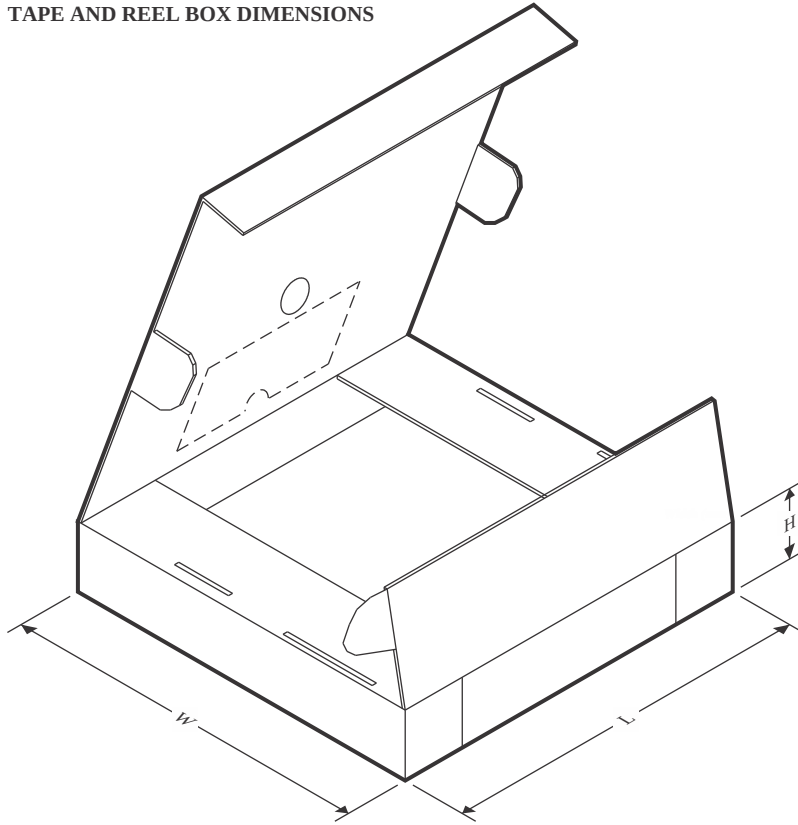
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|-----|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS62601YFFT | DSBGA        | YFF             | 6    | 250 | 180.0              | 8.4                | 1.07    | 1.42    | 0.74    | 4.0     | 8.0    | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|-----|-------------|------------|-------------|
| TPS62601YFFT | DSBGA        | YFF             | 6    | 250 | 182.0       | 182.0      | 20.0        |

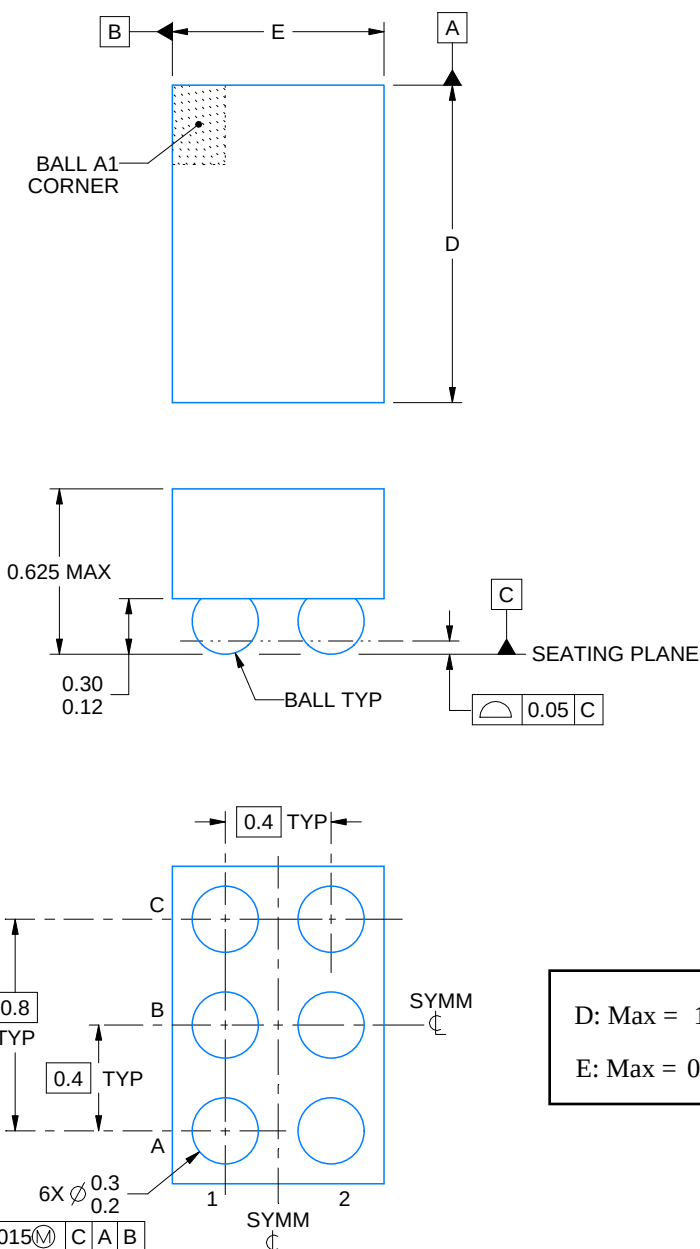
YFF0006



# PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



4223785/A 06/2017

## NOTES:

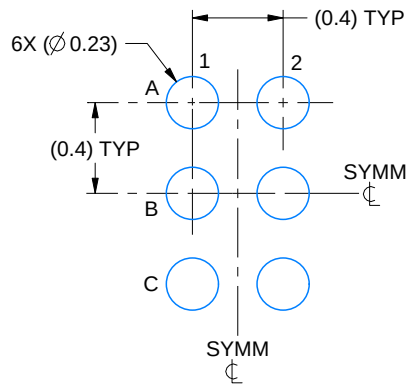
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

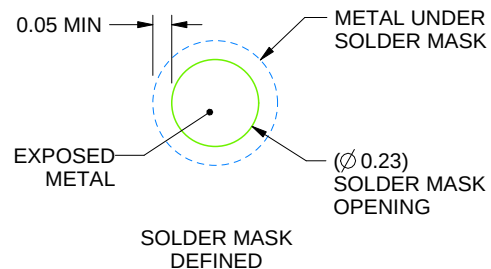
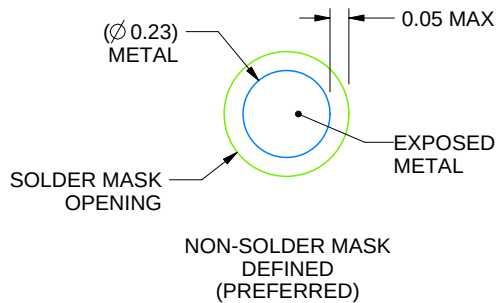
YFF0006

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:30X



SOLDER MASK DETAILS  
NOT TO SCALE

4223785/A 06/2017

NOTES: (continued)

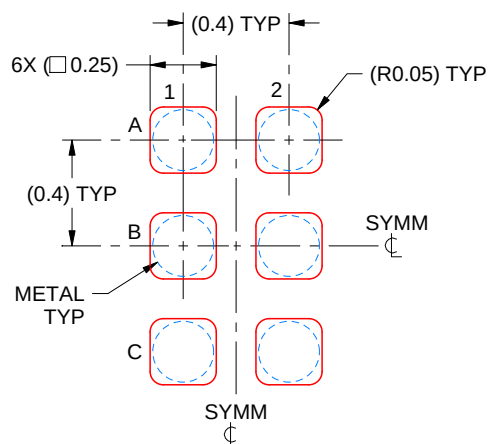
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

## EXAMPLE STENCIL DESIGN

YFF0006

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:35X

4223785/A 06/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2025, Texas Instruments Incorporated